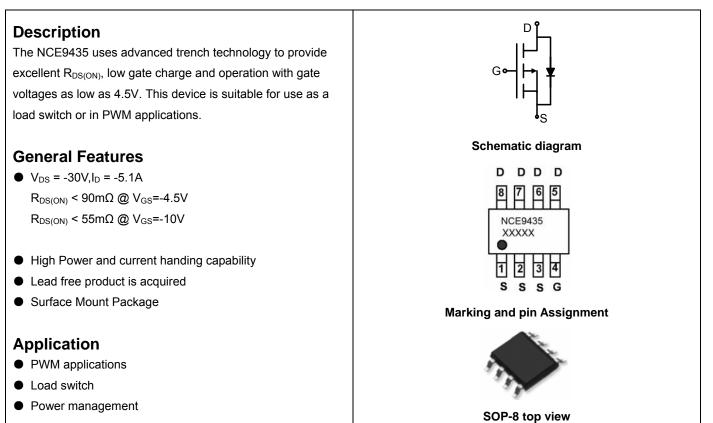


# NCE P-Channel Enhancement Mode Power MOSFET



#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE9435	NCE9435	SOP-8	Ø330mm	12mm	4000 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise noted)

<b>U</b> .	-		
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub>	-5.1	A
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-20	А
Maximum Power Dissipation	PD	2.5	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	50	°C <b>/W</b>
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#### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-30	-33	-	V





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Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-24V, $V_{GS}$ =0V	-	-	-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V		-	±100	nA
On Characteristics (Note 3)	·	•				
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250µA	-1.1	-1.6	-2.1	V
Drain October On Otata Draintean	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-5.1A	-	43	55	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4.2A	-	62	90	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =-15V,I <sub>D</sub> =-5.1A	4	7	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C <sub>lss</sub>		-	980	-	PF
Output Capacitance	C <sub>oss</sub>	– V <sub>DS</sub> =-15V,V <sub>GS</sub> =0V, – F=1.0MHz	-	390	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	135	-	PF
Switching Characteristics (Note 4)	·	·				
Turn-on Delay Time	t <sub>d(on)</sub>		-	14	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =-15V, ID=-1A,	-	12	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10V, $R_{GEN}$ =6 $\Omega$	-	56	-	nS
Turn-Off Fall Time	t <sub>f</sub>			20	-	nS
Total Gate Charge	Qg		-	11	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-15V,I <sub>D</sub> =-5.1A,V <sub>GS</sub> =-10V	-	2.0	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	2.8	-	nC
Drain-Source Diode Characteristics	•				•	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-5.1A	-	-	-1.2	V

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production





# NCE9435

## **Typical Electrical and Thermal Characteristics**

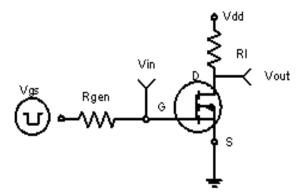
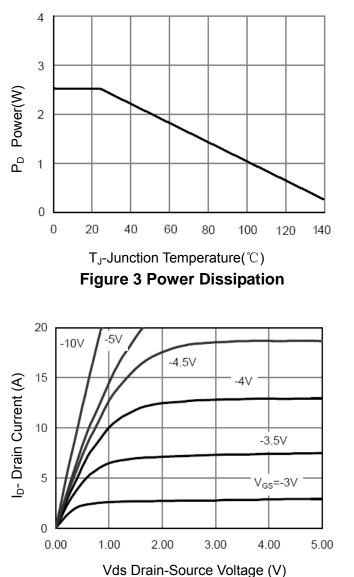


Figure 1:Switching Test Circuit



**Figure 5 Output Characteristics** 

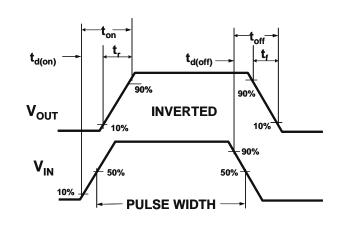
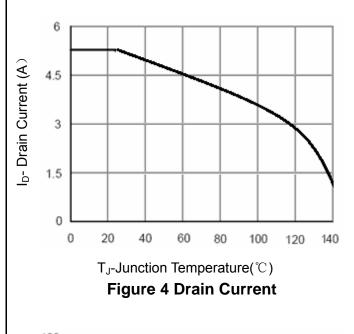


Figure 2:Switching Waveforms



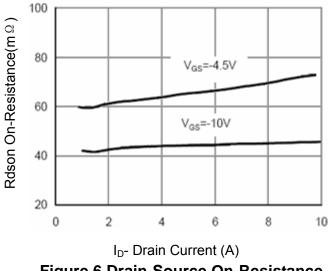
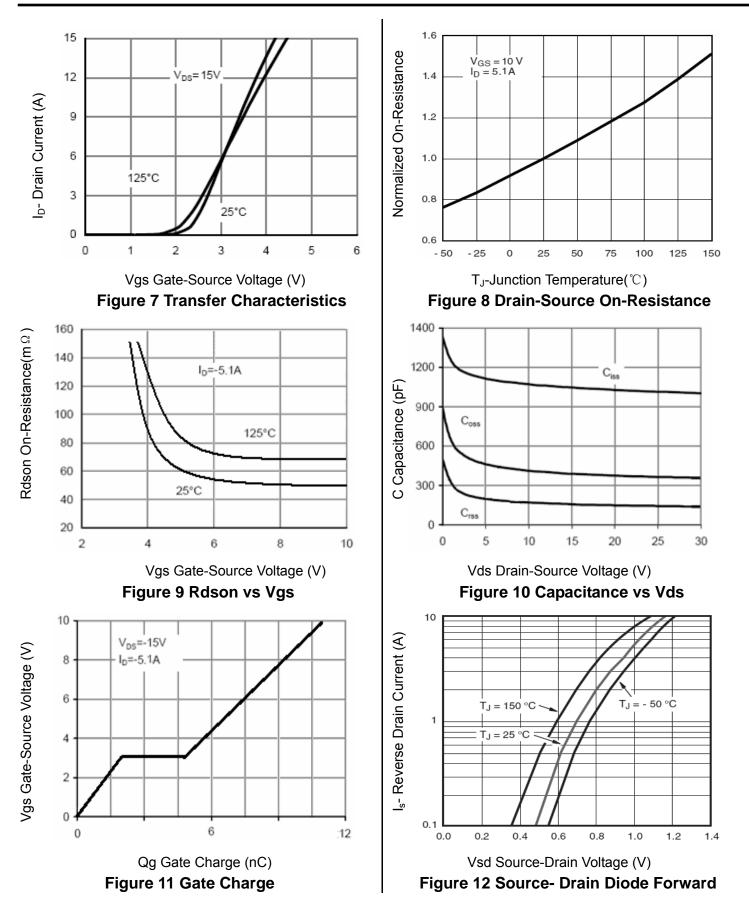


Figure 6 Drain-Source On-Resistance



**Pb Free Product** 

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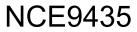


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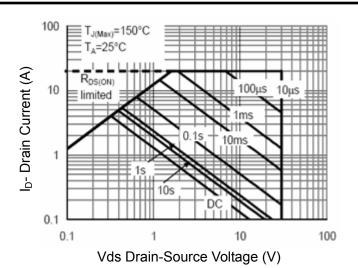


Figure 13 Safe Operation Area

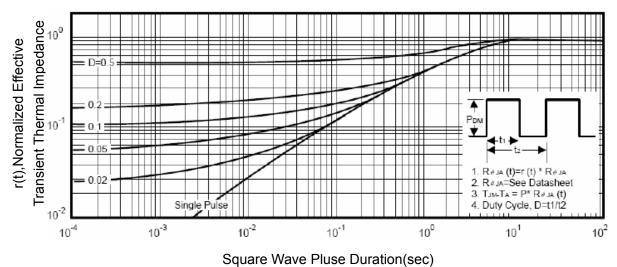


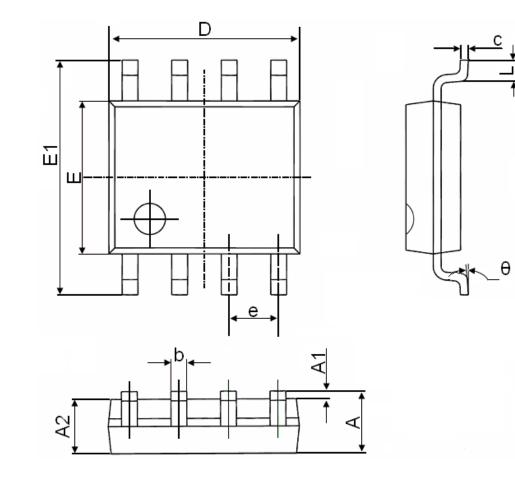
Figure 14 Normalized Maximum Transient Thermal Impedance







# SOP-8 Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	(BSC)	0.050(BSC)		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	







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